

N-Channel MOSFETs (>500V...900V); Package: PG-SOT223-4; VDS (max): 600.0 V; Package: SOT-223; RDS(ON) @ TJ=25°C VGS=10: 6,000.0 mOhm; ID(max) @ TC=25°C: 0.3 A; IDpuls (max): 1.6 A; MOSFET COOL MOS PWR TRANS 650V .3A

Manufacturers	Infineon Technologies Corporation
Package/Case	SOT223
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for SPN01N60C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPN01N60C3 is a part number for a power MOSFET transistor manufactured by Infineon Technologies. Here are some of its features:

Features

- Voltage rating: 600V
- Current rating: 1A
- RDS(on) (on-state resistance): 4.5 ohms
- Package type: SOT-223

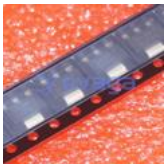
Application

- IRF7416PBF
- STD1NK60Z-1
- STW1NK60Z
- STP1NK60ZFP
- FQP1N60C





Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



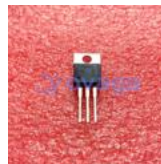
[SPP11N65C3](#)

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TO-220



[SPP07N65C3](#)

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TO-220AB



[SPP07N60S5](#)

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P-TO220-3-1



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PG-TO220



[IRF640NSPBF](#)

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[SPP20N60CFD](#)

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